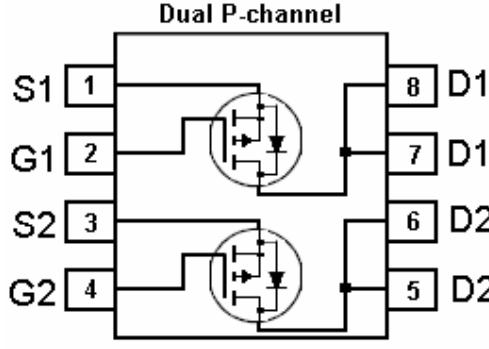




TSM7104D

20V Dual P-Channel Enhancement Mode MOSFET

 <p>SOP-8</p> <p>Pin assignment:</p> <ol style="list-style-type: none"> 1. Source 1 2. Gate 1 3. Source 2 4. Gate 2 5, 6. Drain 2 7, 8. Drain 1 	<p>V_{DS} = - 20V</p> <p>R_{DS(on)}, V_{GS} @ - 4.5V, I_{DS} @ - 2.3A = 130mΩ</p> <p>R_{DS(on)}, V_{GS} @ - 2.5V, I_{DS} @ - 2.0A = 190mΩ</p>																																													
<p>Features</p> <ul style="list-style-type: none"> ✧ Advanced trench process technology ✧ High density cell design for ultra low on-resistance ✧ Excellent thermal and electrical capabilities ✧ Surface mount ✧ Fast switching <p>Ordering Information</p> <table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th style="text-align: left; padding: 2px;">Part No.</th><th style="text-align: left; padding: 2px;">Packing</th><th style="text-align: left; padding: 2px;">Package</th></tr> </thead> <tbody> <tr> <td style="text-align: left; padding: 2px;">TSM7104DCS</td><td style="text-align: left; padding: 2px;">Tape & Reel</td><td style="text-align: left; padding: 2px;">SOP-8</td></tr> </tbody> </table>	Part No.	Packing	Package	TSM7104DCS	Tape & Reel	SOP-8	<p>Block Diagram</p> 																																							
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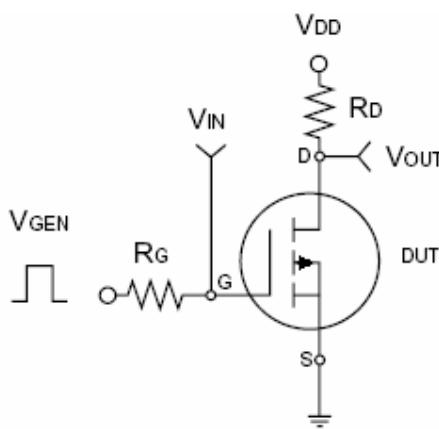
Note: Surface mounted on FR4 board t<=5sec.

Electrical Characteristics

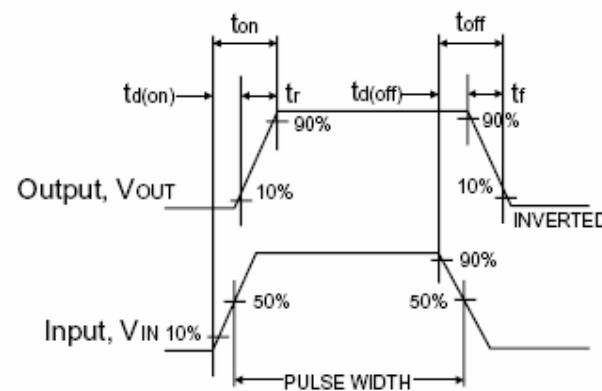
Rate $I_D = -2.3A$, ($T_a = 25^\circ C$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = -250\mu A$	BV_{DSS}	- 20	--	--	V
Drain-Source On-State Resistance	$V_{GS} = -4.5V, I_D = -2.3A$	$R_{DS(ON)}$	--	90	130	$m\Omega$
Drain-Source On-State Resistance	$V_{GS} = -2.5V, I_D = -2.0A$	$R_{DS(ON)}$	--	120	190	
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250\mu A$	$V_{GS(TH)}$	- 0.45	--	--	V
Zero Gate Voltage Drain Current	$V_{DS} = -16V, V_{GS} = 0V$	I_{DSS}	--	--	- 1.0	μA
Gate Body Leakage	$V_{GS} = \pm 8V, V_{DS} = 0V$	I_{GSS}	--	--	± 100	nA
Forward Transconductance	$V_{DS} = -5V, I_D = -2.3A$	g_{fs}	--	6.5	--	S
Dynamic						
Total Gate Charge	$V_{DS} = -6V, I_D = -2.3A, V_{GS} = -4.5V$	Q_g	--	5.4	10	nC
Gate-Source Charge		Q_{gs}	--	0.8	--	
Gate-Drain Charge		Q_{gd}	--	1.1	--	
Turn-On Delay Time	$V_{DD} = -6V, R_L = 6\Omega, I_D = -1A, V_{GEN} = -4.5V, R_G = 6\Omega$	$t_{d(on)}$	--	5	25	nS
Turn-On Rise Time		t_r	--	19	60	
Turn-Off Delay Time		$t_{d(off)}$	--	95	110	
Turn-Off Fall Time		t_f	--	65	80	
Input Capacitance	$V_{DS} = -6V, V_{GS} = 0V, f = 1.0MHz$	C_{iss}	--	447	--	pF
Output Capacitance		C_{oss}	--	127	--	
Reverse Transfer Capacitance		C_{rss}	--	80	--	
Source-Drain Diode						
Max. Diode Forward Current		I_S	--	--	- 1.6	A
Diode Forward Voltage	$I_S = -1.6A, V_{GS} = 0V$	V_{SD}	--	- 0.8	- 1.2	V

Note : pulse test: pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$

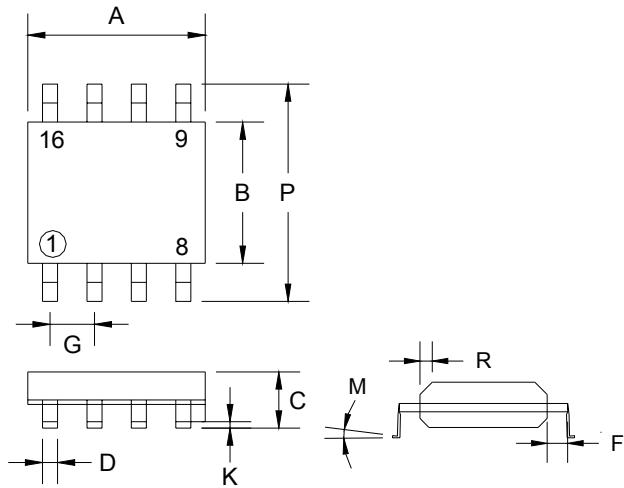


Switching Test Circuit



Switchin Waveforms

SOP-8 Mechanical Drawing



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.196
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 (typ)		0.05 (typ)	
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019